



PNP SMALL SIGNAL TRANSISTOR IN SOT23

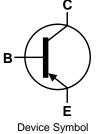
Features

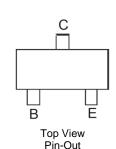
- Ideally Suited for Automatic Insertion
- Complementary NPN Types: BC846 BC848
- For Switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)







Ordering Information (Notes 4 & 5)

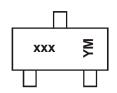
Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC856A-7-F	AEC-Q101	K3A	7	3,000
BC856AQ-7-F	Automotive	K3A	7	3,000
BC856B-7-F	AEC-Q101	K3B	7	3,000
BC856BQ-7-F	Automotive	K3B	7	3,000
BC856B-13-F	AEC-Q101	K3B	13	10,000
BC856BQ-13-F	Automotive	K3B	13	10,000
BC857A-7-F	AEC-Q101	K3A	7	3,000

Product	Compliance	Marking	Reel Size (inches)	Quantity per Reel
BC857B-7-F	AEC-Q101	K3B	7	3,000
BC857BQ-7-F	Automotive	K3B	7	3,000
BC857B-13-F	AEC-Q101	K3B	13	10,000
BC857C-7-F	AEC-Q101	K3G	7	3,000
BC857C-13-F	AEC-Q101	K3G	13	10,000
BC858A-7-F	AEC-Q101	K3A	7	3,000
BC858B-7-F	AEC-Q101	K3B	7	3,000
BC858C-7-F	AEC-Q101	K3G	7	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product_compliance_definitions/.
- 5. Tape width is 8mm. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



xxx = Product Type Marking Code(Please see Ordering Information)

YM = Date Code Marking

Y or \overline{Y} = Year (ex: A = 2013)

M or \overline{M} = Month (ex: 9 = September)

Date Code Key

Year	2010	20)11	2012	2	013	2014		2015	2016		2017
Code	Х		Υ	Z		Α	В		С	D		Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteris	stic	Symbol	Value	Unit
	BC856		-80	
Collector-Base Voltage	BC857	V_{CBO}	-50	V
	BC858		-30	
	BC856		-65	
Collector-Emitter Voltage	BC857	V _{CEO}	-45	V
	BC858		-30	
Emitter-Base Voltage		V_{EBO}	-5.0	V
Continuous Collector Current		Ic	-100	mA
Peak Collector Current		I _{CM}	-200	mA
Peak Emitter Current		I _{EM}	-200	mA
Peak Base Current		I _{BM}	-200	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Characteristic	Зунион	value	Offit	
Power Dissipation	(Note 6)		310	mW
Power Dissipation	(Note 7)	- P _D	350	IIIVV
Thermal Decistores, Junction to Ambient	(Note 6)	7	403	°C/W
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{\theta JA}$	357	C/VV
Thermal Resistance, Junction to Leads (Note 8)		R ₀ JL	350	°C/W
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-65 to +150	°C

ESD Ratings (Note 9)

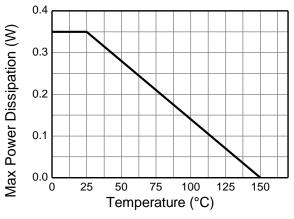
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

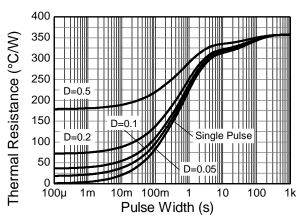
Notes:

- 6. For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air For a device mounted on minimum recommended pad layout 102 copper that is conditions whilst operating in a steady-state.
 Same as Note 6, except the device is mounted on 15 mm x 15mm 1oz copper.
 Thermal resistance from junction to solder-point (at the end of the leads).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



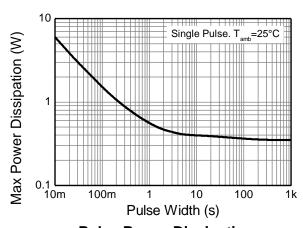
Thermal Characteristics and Derating Information





Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Cha	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC856		-80					
Collector-Base Breakdown V	oltage	BC857	BV _{CBO}	-50	_	_	V	$I_C = -10\mu A$	
	_	BC858	1	-30					
Collector-Emitter Breakdown Voltage (Note 10)		BC856		-65					
		BC857	BV_{CEO}	-45	_	_	V	$I_C = -10mA$	
(Note 10)		BC858		-30					
Emitter-Base Breakdown Vol	tage		BV _{EBO}	-5	_	_	V	$I_E = -1\mu A$	
Collector Cutoff Current	Collector Cutoff Current		I _{CBO}			-15	nA	$V_{CB} = -30V$	
Collector Catoli Carrent			ICBO			-4	μΑ	$V_{CB} = -30V, T_J = +150$ °C	
		BC856				-15		$V_{CE} = -80V$	
Collector Emitter Cutoff Curre	ent	BC857	I _{CES}	_	_	-15	nA	$V_{CE} = -50V$	
		BC858				-15		$V_{CE} = -30V$	
Emitter-Base Cutoff Current			I _{EBO}	_	_	-100	nA	$V_{EB} = -5V$	
Carall Cianal Comment Caia	BC856A / E	3C857A / BC858A			200				
Small Signal Current Gain (Note 10)	BC856B / E	3C857B / BC858B	h _{fe}	_	330	_	_		
(Note 10)	BC857	'C / BC858C			600				
	BC856A / E	3C857A / BC858A			2.7			1	
Input Impedance (Note 10)		3C857B / BC858B	h _{ie}	_	4.5	_	kΩ		
	BC857C / BC858C				8.7			$I_C = -2.0 \text{mA}, V_{CE} = -5 \text{V}$ f = 1.0kHz	
Output Admittance	BC856A / BC857A / BC858A				18				
(Note 10)		3C857B / BC858B	h _{oe}	<u> </u>	30	_	μS		
(14010-10)		C / BC858C			60]	
Reverse Voltage Transfer		3C857A / BC858A			1.5x10 ⁻⁴				
Ratio (Note 10)		3C857B / BC858B	h _{re}	—	2x10 ⁻⁴] —	_		
11410 (11616 16)		C / BC858C			3x10 ⁻⁴				
		3C857A / BC858A		125	180	250			
DC Current Gain (Note 10)		3C857B / BC858B	h _{FE}	220	290	475	_	$I_C = -2.0 \text{mA}, V_{CE} = -5 \text{V}$	
	BC857	C / BC858C		420	520	800			
Collector-Emitter Saturation	Voltage (Note 1)	וו	V _{CE(sat)}	_	-75	-300	mV	$I_C = -10mA, I_B = -0.5mA$	
Concetor Emitter Cataration	voltage (Note 1	3)	V CE(sat)		-250	-650	1117	$I_C = -100 \text{mA}, I_B = -5.0 \text{mA}$	
Base-Emitter Turn-On Voltage	e (Note 10)		V _{BE(on)}	-600	-650	-750	mV	$I_C = -2mA$, $V_{CE} = -5V$	
Base-Emilier Turn-On Voltag	ge (Note 10)		V BE(on)	_	_	-820	IIIV	$I_C = -10 \text{mA}, V_{CE} = -5 \text{V}$	
Base-Emitter Saturation Volta	age (Note 10)		V==()	_	-700		mV	$I_C = -10mA$, $I_B = -0.5mA$	
Base-Emilier Saturation voils	age (Note 10)		V _{BE(sat)}		-850	-1100	IIIV	$I_C = -100 \text{mA}, I_B = -5 \text{mA}$	
Output Capacitance			C_{obo}	_	3	_	pF	$V_{CB} = -10V, f = 1.0MHz$	
Transition Frequency			f⊤	100	200	_	MHz	$V_{CE} = -5V, I_{C} = -10mA,$ f = 100MHz	
Noise Figure			NF	_	2	10	dB	$\begin{aligned} &V_{CE} = \text{-5V, } I_{C} = \text{-200}\mu\text{A} \\ &R_{S} = 2k\Omega, f = 1k\text{Hz} \\ &\Delta f = 200\text{Hz} \end{aligned}$	

Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

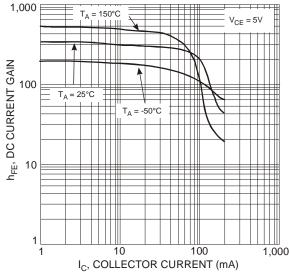
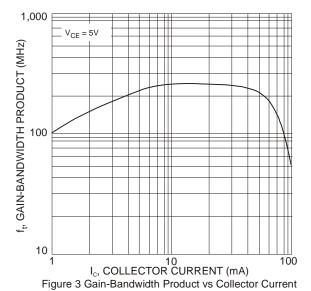


Figure 1 Typical DC Current Gain vs. Collector Current



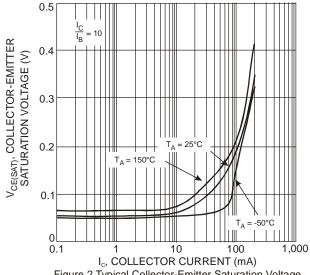
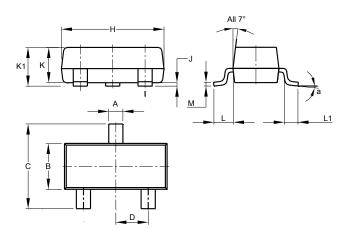


Figure 2 Typical Collector-Emitter Saturation Voltage vs. Collector Current



Package Outline Dimensions

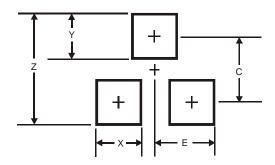
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а		8°					
All	Dimens	ions in	mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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